

Monte Carlo and Charge Transport Simulation of Pixel Detector Systems

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Abstract:

This thesis is about simulation of semiconductor X-ray and particle detectors. The simulation of a novel coating for solid state neutron detectors is discussed as well as the implementation of a simulation framework for hybrid pixel detectors.

Today's most common thermal neutron detectors are proportional counters, that use ^3He gas in large tubes or multi wire arrays. Global nuclear disarmament and the increase in use for homeland security applications has created a shortage of the gas which poses a problem for neutron spallation sources that require higher resolution and larger sensors. In this thesis a novel material and clean room compatible process for neutron conversion are discussed. Simulations and fabrication have been executed and analysed in measurements. It has been proven that such a device can be fabricated and detect thermal neutrons.

Spectral imaging hybrid pixel detectors like the Medipix chip are the most advanced imaging systems currently available. These chips are highly sophisticated with several hundreds of transistors per pixel to enable features like multiple thresholds for noise free photon counting measurements, spectral imaging as well as time of arrival measurements. To analyse and understand the behaviour of different sensor materials bonded to the chip and to improve development of future generations of the chip simulations are necessary. Generally, all parts of the detector system are simulated independently. However, it is favourable to have a simulation framework that is able to combine Monte Carlo particle transport, charge transport in the sensor as well as analogue and digital response of the pixel read-out electronics. This thesis aims to develop such a system that has been developed with Geant4 and analytical semiconductor and electronics models. Furthermore, it has been verified with data from measurements with several Medipix and Timepix sensors as well as TCAD simulations.

Results show that such a framework is feasible even for imaging simulations. It shows great promise to be able to be extended with future pixel detector designs and semiconductor materials as well as neutron converters to aim for next generation imaging devices.